

MiniSKiiP® 2

3-phase bridge rectifier + brake chopper

SKiiP 28ANB16V10

**Target Data** 

#### **Features**

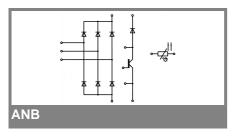
- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

### **Typical Applications\***

Input bridge for Inverter up to 39 kVA

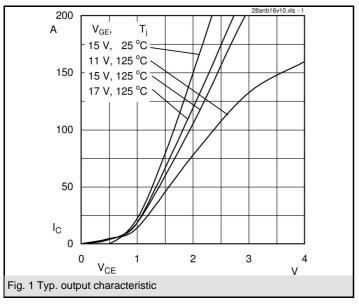
#### **Remarks**

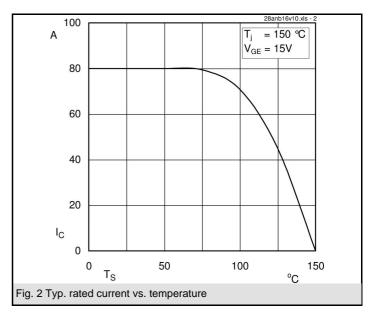
• V<sub>CEsat</sub> , V<sub>F</sub> = chip level value

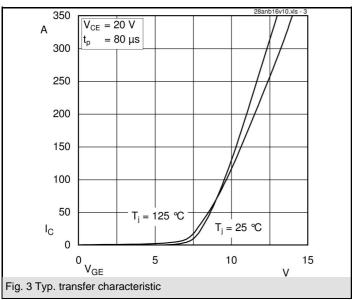


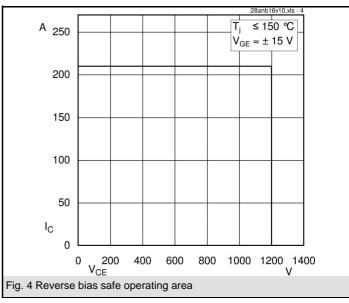
<b>Absolute Maximum Ratings</b> T <sub>s</sub> = 25 °C, unless otherwise specified								
Symbol	Conditions	Values	Units					
IGBT - Chopper								
$V_{CES}$		1200	V					
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	118 (88)	Α					
I <sub>CRM</sub>		210	Α					
$V_{GES}$		± 20	V					
$T_j$		- 40 <b>+</b> 150	°C					
Diode - Chopper								
I <sub>F</sub>	T <sub>s</sub> = 25 (70) °C	118 (88)	Α					
I <sub>FRM</sub>		210	Α					
$T_j$		- 40 <b>+</b> 150	°C					
Diode - Rectifier								
$V_{RRM}$		1600	V					
I <sub>F</sub>	T <sub>s</sub> = 70 °C	83	Α					
I <sub>FSM</sub>	$t_{\rm p}$ = 10 ms, sin 180 °, $T_{\rm i}$ = 25 °C	1000	Α					
i²t	$t_{\rm p}$ = 10 ms, sin 180 °, $T_{\rm i}$ = 25 °C	6600	A²s					
$T_j$		- 40 <b>+</b> 150	°C					
Module			u.					
I <sub>tRMS</sub>	per power terminal (20 A / spring)	80	Α					
T <sub>stg</sub>		- 40 <b>+</b> 125	°C					
V <sub>isol</sub>	AC, 1 min.	2500	V					

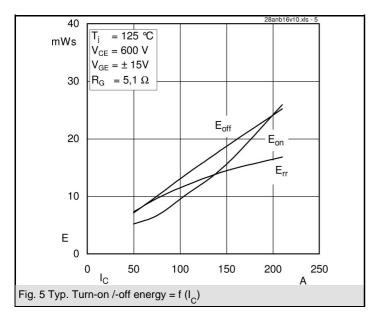
Characteristics		$T_s$ = 25 °C, unless otherwise specified						
Symbol	Conditions	min.	typ.	max.	Units			
IGBT - Chopper								
$\begin{array}{c} V_{CEsat} \\ V_{GE(th)} \\ V_{CE(TO)} \\ r_{T} \\ C_{ies} \\ C_{res} \\ R_{th(j-s)} \end{array}$	$\begin{split} &   \text{$I_{\text{Cnom}}$ = 105 \text{ A, T}_{j} = 25 \text{ (125) °C}} \\ & \text{$V_{\text{GE}}$ = $V_{\text{CE}}$, $I_{\text{C}}$ = 3 mA} \\ & \text{$T_{j}$ = 25 \text{ (125) °C}} \\ & \text{$T_{j}$ = 25 \text{ (125) °C}} \\ & \text{$V_{\text{CE}}$ = 25 V, $V_{\text{GE}}$ = 0 V, $f$ = 1 MHz} \\ & \text{$V_{\text{CE}}$ = 25 V, $V_{\text{GE}}$ = 0 V, $f$ = 1 MHz} \\ & \text{$V_{\text{CE}}$ = 25 V, $V_{\text{GE}}$ = 0 V, $f$ = 1 MHz} \\ & \text{$p_{\text{CE}}$ = 10 MHz} \\ \end{split}$	5	1,7 (2) 5,8 1 (0,9) 6,7 (10) 8,4 1,5 1,1	2,1 (2,4) 6,5 1,2 (1,1) 8,6 (12)	V V MΩ nF nF nF			
t <sub>d(on)</sub>	under following conditions		65 30		ns			
$\begin{aligned} &t_r \\ &t_{d(off)} \\ &t_f \\ &E_{on} \\ &E_{off} \end{aligned}$ $\begin{aligned} &\textbf{Diode - C} \\ &V_F = V_{EC} \\ &V_{(TO)} \\ &r_T \\ &R_{th(j-s)} \end{aligned}$	$V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$ $I_{Cnom} = 105 \text{ A}, T_j = 125^{\circ}\text{C}$ $R_{Gon} = R_{Goff} = 5,1 \Omega$ inductive load  hopper $I_{Fnom} = 105 \text{ A}, T_j = 25 (125) ^{\circ}\text{C}$ $T_j = 25 (125) ^{\circ}\text{C}$ $T_j = 25 (125) ^{\circ}\text{C}$ per diode		465 95 10,1 13,6 1,6 (1,6) 1 (0,8) 5,7 (7,6) 0,55	1,8 (1,8) 1,1 (0,9) 6,7 (8,6)	ns ns ns mJ mJ V V mΩ K/W			
I <sub>RRM</sub> Q <sub>rr</sub> E <sub>rr</sub>	under following conditions $I_{Fnom} = 105 \text{ A}, V_R = 600 \text{ V}$ $V_{GE} = 0 \text{ V}, T_j = 125 ^{\circ}\text{C}$ $di_F/dt = 4350 \text{ A/}\mu\text{s}$		180 26 11,8		Α μC mJ			
Diode - Rectifier								
$V_F$ $V_{(TO)}$ $r_T$ $R_{th(j-s)}$	$I_{Fnom} = 75 \text{ A}, T_j = 25 \text{ °C}$ $T_j = 150 \text{ °C}$ $T_j = 150 \text{ °C}$ per diode		1,2 0,8 7 0,7		V V mΩ K/W			
· -	ure Sensor	1			,			
R <sub>ts</sub>	3 %, T <sub>r</sub> = 25 (100) °C		1000(1670)		Ω			
Mechanical Data								
w M <sub>s</sub>	Mounting torque	2	65	2,5	g Nm			

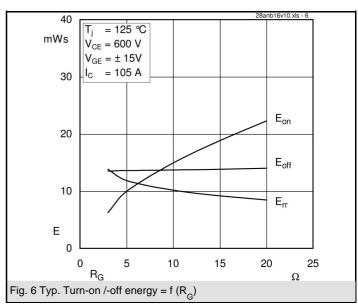


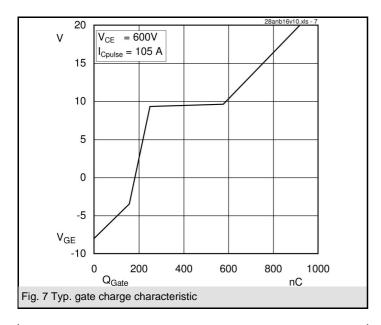


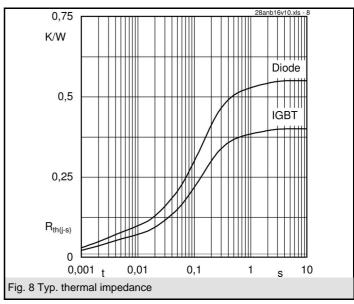


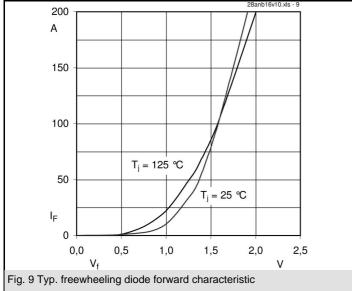


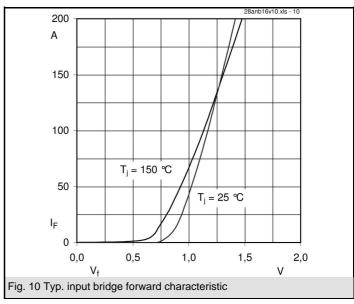


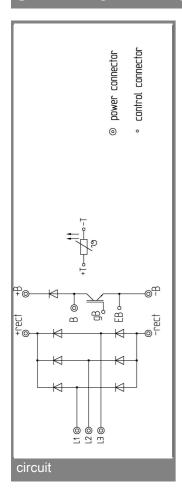


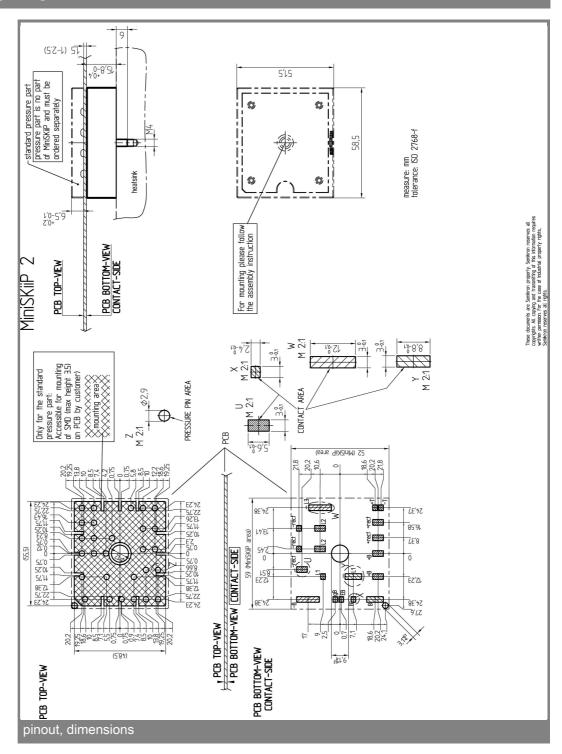












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

<sup>\*</sup> The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.